# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## LIXYS

### Standard Power MOSFET

IXTH 16P20

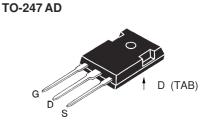
### $V_{DSS}$ = -200 V $I_{D25}$ = -16 A $R_{DS(on)}$ = 0.16 Ω

P-Channel Enhancement Mode Avalanche Rated

#### **Preliminary Data Sheet**

		03		
Symbol	TestConditions	Maximum	Maximum Ratings	
V <sub>DSS</sub>	$T_{J} = 25^{\circ}C$ to $150^{\circ}C$	-200	V	
V <sub>DGR</sub>	$T_{_J}$ = 25°C to 150°C; $R_{_{GS}}$ = 1 M $\Omega$	-200	V	
V <sub>GS</sub>	Continuous	±20	V	
V <sub>GSM</sub>	Transient	±30	V	
D25	$T_c = 25^{\circ}C$	-16	А	
l <sub>DM</sub>	$T_{c}$ = 25°C, pulse width limited by $T_{J}$	-64	А	
I <sub>AR</sub>	$T_c = 25^{\circ}C$	-16	А	
E <sub>AR</sub>	$T_c = 25^{\circ}C$	30	mJ	
P <sub>D</sub>	$T_c = 25^{\circ}C$	300	W	
T		-55 +150	°C	
T <sub>JM</sub>		150	°C	
T <sub>stg</sub>		-55 +150	°C	
TL	Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s	300	°C	
M <sub>d</sub>	Mounting torque	1.13/10	Nm/lb.in.	
Weight		6	g	

Symbol	Test Conditions	Cha (T <sub>J</sub> = 25°C, unless o <b>min.</b>	otherwi	istic Va se speci   max.	
V <sub>DSS</sub>	$V_{_{GS}}$ = 0 V, $I_{_{D}}$ = -250 $\mu$ A	-200			V
V <sub>GS(th)</sub>	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250 \ \mu\text{A}$	-3.0		-5.0	V
I <sub>GSS</sub>	$V_{_{\rm GS}} = \pm 20  V_{_{\rm DC}},  V_{_{\rm DS}} = 0$			±100	nA
I <sub>DSS</sub>	$V_{\text{DS}} = 0.8 \cdot V_{\text{DSS}}$ $V_{\text{GS}} = 0 \text{ V}$	T <sub>J</sub> = 25°C T <sub>J</sub> = 125°C		-25 -1	μA mA
R <sub>DS(on)</sub>	$V_{gs} = -10 \text{ V}, \text{ I}_{p} = 0.5 \cdot \text{ I}_{p25}$			0.16	Ω



G = Gate, S = Source, D = Drain, TAB = Drain

#### Features

- International standard package JEDEC TO-247 AD
- Low R<sub>DS (on)</sub> HDMOS<sup>™</sup> process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance (<5 nH)
  - easy to drive and to protect

#### Applications

- High side switching
- Push-pull amplifiers
- DC choppers
- · Automatic test equipment

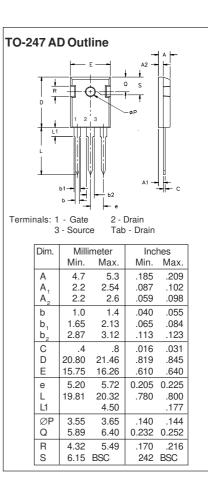
#### **Advantages**

- Easy to mount with 1 screw (isolated mounting screw hole)
- Space savings
- High power density

## LIXYS

Source Drain Diede

Symbol		aracteristic Values otherwise specified)		
	min.	typ.	max.	
<b>g</b> <sub>fs</sub>	$V_{_{DS}} = -10 \text{ V}; I_{_{D}} = I_{_{D25}}, \text{ pulse test}$ 6	10	S	
C <sub>iss</sub>	)	2800	pF	
C <sub>oss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = -25 V, f = 1 MHz	550	pF	
C <sub>rss</sub>	J	240	pF	
t <sub>d(on)</sub>		33	ns	
t <sub>r</sub>	$V_{_{ m GS}}$ = -10 V, $V_{_{ m DS}}$ = 0.5 $V_{_{ m DSS}}$ , $I_{_{ m D}}$ = 0.5 $I_{_{ m D25}}$	26	ns	
t <sub>d(off)</sub>	$R_{g} = 4.7 \Omega (External)$	65	ns	
t <sub>r</sub>	J	25	ns	
Q <sub>g(on)</sub>	)	95	nC	
$\mathbf{Q}_{gs}$	$V_{GS} = -10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, \text{ I}_{D} = 0.5 \text{ I}_{D25}$	27	nC	
$\mathbf{Q}_{gd}$	J	40	nC	
R <sub>thJC</sub>			0.42 K/W	
R <sub>thCS</sub>		0.25	K/W	



Source-Drai		$(T_1 = 25^{\circ}C, \text{ unless otherwise specified})$		
Symbol	Test Conditions min		max.	icu)
l <sub>s</sub>	V <sub>GS</sub> = 0		-16	A
I <sub>sm</sub>	Repetitive; pulse width limited by $\mathrm{T}_{_{\mathrm{JM}}}$		-64	Α
V <sub>SD</sub>	$\begin{split} I_{_{F}} &= I_{_{S}},  V_{_{GS}} = 0  V, \\ \text{Pulse test, } t \leq 300  \mu\text{s, duty cycle } d \leq 2  \% \end{split}$		-3	V
t <sub>rr</sub>	$I_{_{\rm F}}$ = $I_{_{\rm S}}$ , di/dt = 100 A/µs, $V_{_{\rm R}}$ = -50 V	250		ns

IXYS reserves the right to change limits, test conditions, and dimensions.

Characteristic Values